INTERNATIONAL GEMOLOGICAL INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

October 19, 2026

IGI Report Number	LG849657670
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	CUT CORNERED RECTANGULAR MODIFIED BRILLIANT
Measurements	8.14 X 5.48 X 3.67 MM

GRADING RESULTS

Carat Weight	1.51 CARAT
Color Grade	E
Clarity Grade	VVS 1

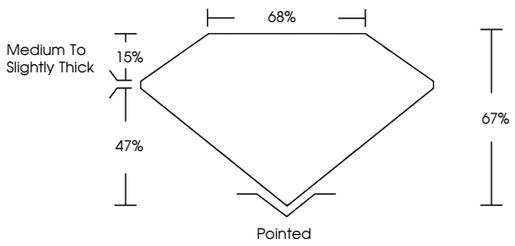
ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	LG849657670

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process.
Type IIa

LG849657670
Report verification at igi.org

PROPORTIONS





Sample Image Used

COLOR

D	E	F	G	H	I	J	Faint	Very Light	Light

CLARITY

FL	IF	VVS 1 - 2	VS 1 - 2	SI 1 - 2	I 1 - 3
Flawless	Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included

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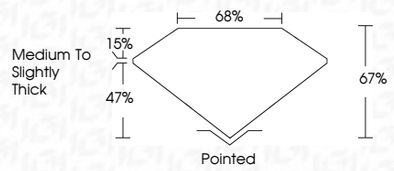
www.igi.org

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IGI

October 19, 2026
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CUT CORNERED RECT. MODIFIED BRILLIANT
8.14 X 5.48 X 3.67 MM
Carat Weight 1.51 CARAT
Color Grade E
Clarity Grade VVS 1
Depth 67%
Table 68%
Girdle Medium To Slightly Thick
Culet Pointed
Polish EXCELLENT
Symmetry EXCELLENT
Fluorescence NONE
Inscription(s) LG849657670
Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa